NSN 5961-00-929-3055

Unitized Semiconductor Device Rectifier - Page 1 of 1



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Special Features:

Silicon, single phase full wave bridge; 200v peak inverse voltage; 140v rms voltage; 1.5 amp average rectified current at 25 degrees c and 1.05 amp at 100 degrees c; 10 amp recurrent surge current at 25 degrees c; hermetically sealed units; molded case; 0.875 in. Dia; 0.250 in. H; 4 solder stud type terminals 0.137 in. Maximum h; terminals equally spaced on 0.625 in. Diameter circle; one 0.144 in. Diameter unthreaded mtg hole counterbored 0.310 in. In. Diameter by 0.125 in. Deep through center of case; m55.0 to p150.0 degrees c operating temp; storage temp range: minus 55.0 to 150.0 degrees celcius

N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

Shelf Life:

A503j0